

**ISP814X, ISP824X, ISP844X
ISP814, ISP824, ISP844**

**HIGH DENSITY A.C. INPUT
PHOTOTRANSISTOR OPTICALLY
COUPLED ISOLATORS**



APPROVALS

- UL recognised, File No. E91231

'X' SPECIFICATION APPROVALS

- VDE 0884 approval pending
- ISP814X - Certified to EN60950 by the following Test Bodies :-
 - Nemko - Certificate No. P96102022
 - Fimko - Registration No. 192313-01..25
 - Semko - Reference No. 9639052 01
 - Demko - Reference No. 305969
 ISP824X, ISP844X - EN60950 pending

DESCRIPTION

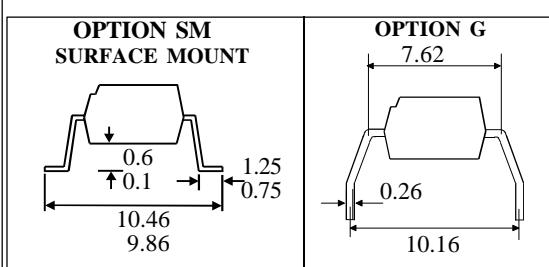
The ISP814, ISP824, ISP844 series of optically coupled isolators consist of two infrared light emitting diodes connected in inverse parallel and NPN silicon photo transistors in space efficient dual in line plastic packages.

FEATURES

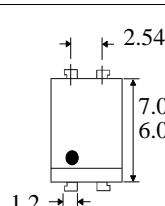
- Options :-
10mm lead spread - add G after part no.
Surface mount - add SM after part no.
Tape&reel - add SMT&R after part no.
- High Isolation Voltage (5.3kV_{RMS}, 7.5kV_{PK})
- AC or polarity insensitive input
- All electrical parameters 100% tested
- Custom electrical selections available

APPLICATIONS

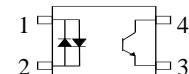
- Computer terminals
- Industrial systems controllers
- Telephone sets, Telephone exchangers
- Signal transmission between systems of different potentials and impedances



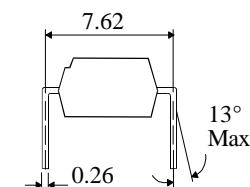
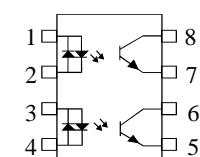
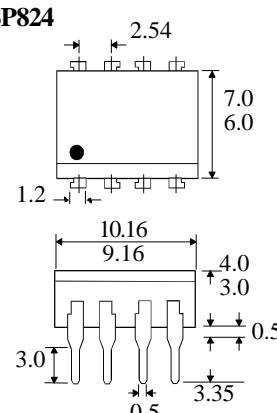
**ISP814X
ISP814**



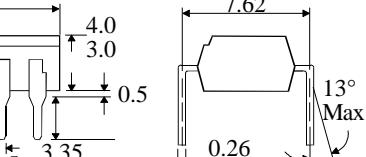
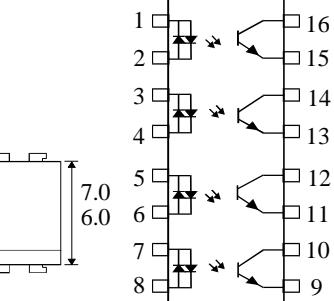
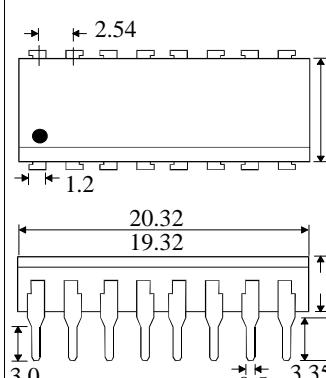
Dimensions in mm



**ISP824X
ISP824**



**ISP844X
ISP844**



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ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)

Storage Temperature	—	-55°C to + 125°C
Operating Temperature	—	-55°C to + 100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)		260°C

INPUT DIODE

Forward Current	—	± 50mA
Power Dissipation	—	70mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV _{CEO}	—	35V
Emitter-collector Voltage BV _{ECO}	—	6V
Power Dissipation	—	150mW

POWER DISSIPATION

Total Power Dissipation	—	200mW
(derate linearly 2.67mW/°C above 25°C)		

ELECTRICAL CHARACTERISTICS (T_A = 25°C Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V _F)		1.2	1.4	V	I _F = ± 20mA
Output	Collector-emitter Breakdown (BV _{CEO}) (Note 2)	35			V	I _C = 1mA
	Emitter-collector Breakdown (BV _{ECO})	6			V	I _E = 100µA
	Collector-emitter Dark Current (I _{CEO})			100	nA	V _{CE} = 20V
Coupled	Current Transfer Ratio (CTR) (Note 2) ISP814, ISP824, ISP844 ISP814A, ISP824A, ISP844A	20		300	%	± 1mA I _F , 5V V _{CE}
		50		150	%	
	Collector-emitter Saturation Voltage V _{CE (SAT)}			0.2	V	± 20mA I _F , 1mA I _C
	Input to Output Isolation Voltage V _{ISO}	5300			V _{RMS}	See note 1
		7500			V _{PK}	See note 1
	Input-output Isolation Resistance R _{ISO}	5x10 ¹⁰			Ω	V _{IO} = 500V (note 1)
	Output Rise Time tr	4		18	µs	V _{CE} = 2V ,
	Output Fall Time tf	3		18	µs	I _C = 10mA, R _L = 100Ω

Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

